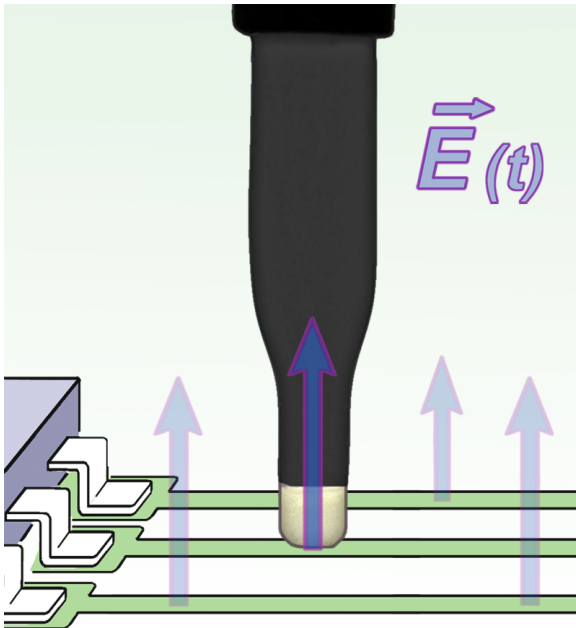


RF-E 10

电场探头 (30MHz-3GHz)



Short description

RF-E 10型电场探头的电极位于探头下边，约0.2mm宽，可以定位最小的电场源，例如0.1mm宽的导线，高引脚数集成电路的单个引脚。

The RF-E 10 is a passive near-field probe. It has a higher resolution than the RF-E 02 and RF-E 05 probes. Because the probe head should be positioned directly onto the measuring object (high electrical field strength), it is not suitable for measurements within high-scale ranges. This can be done using RF-E 05 and RF-E 02. The E-field probe is small and handy. It has a current attenuating sheath and its upper side is electrically shielded. It can be connected to a spectrum analyzer or an oscilloscope with a 50 Ω input. The E-field probe does not have an internal terminating resistance of 50 Ω .

Technical parameters

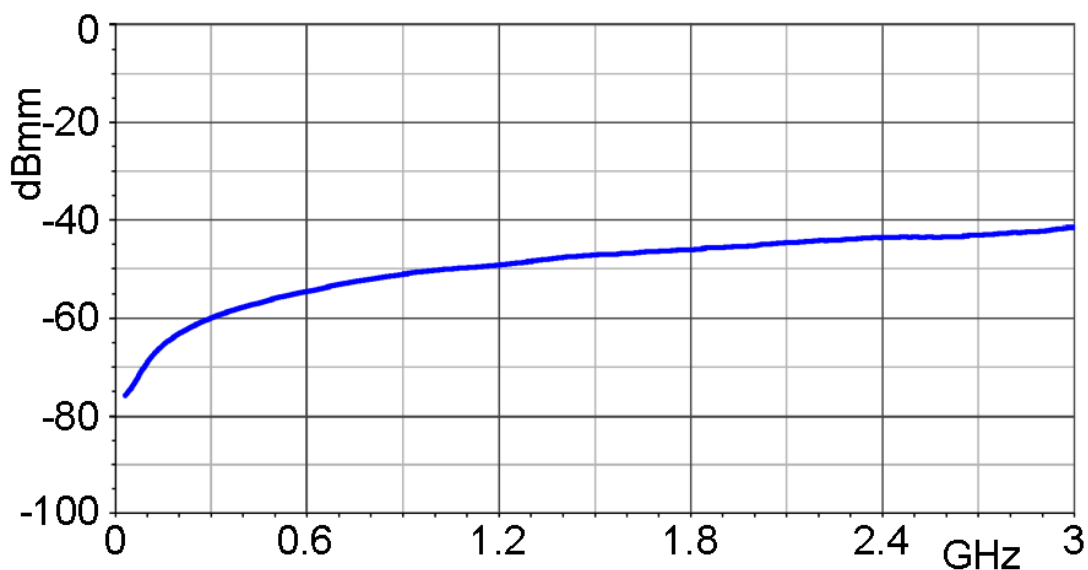
频率范围	30 MHz ... 3 GHz
分辨率	≈ 0.2 mm
探头尺寸	$\approx (0.5 \times 2)$ mm
输出接口	SMB, male, jack
重量	15 g

RF-E 10

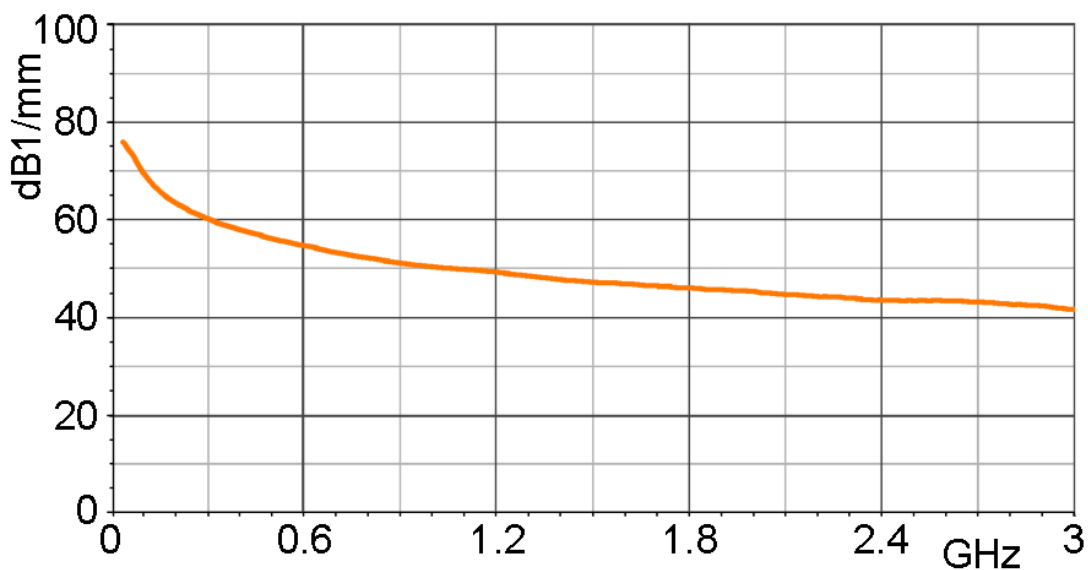
电场探头 (30MHz-3GHz)

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频率特性 [dBμV] / [dBμV/mm]



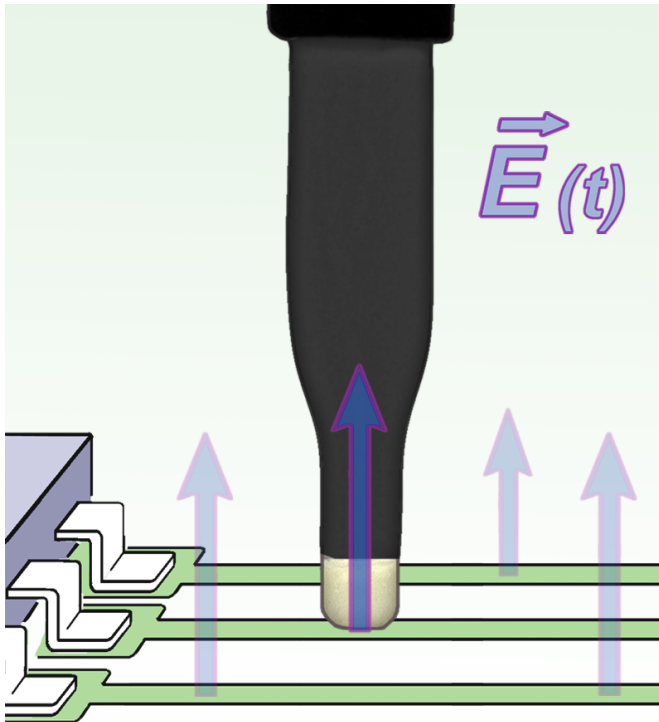
电场校正曲线 [dBμV/mm] / [dBμV]



RF-E 10

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Probe head

